

## T498D476M010ZTE600

Obsolete

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 47 uF, 20%, 10 VDC, SMD, Molded, High Temperature, N/A, 600 mOhms, 7343, Height Max = 3.1mm



### General Information

Series	B45196P
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Notes	Obsolete.

### Dimensions

Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
K	1.8mm TYP

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	750

### Specifications

Capacitance	47 uF
Capacitance Tolerance	20%
Voltage DC	10 VDC (85C), 7.97 VDC (125C), 6.7 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	0.6 Ohms (100kHz)
Ripple Current	500 mAmps (25C), 450 mAmps (85C), 200 mAmps (125C)
Leakage Current	4.7 uA